3-channel BTL driver for CD Players BA6199FP

The BA6199FP, an IC for CD players, has an internal 3-channel H-bridge BTL power driver, 5V regulator (attached PNP transistor required), standard operational amplifier, and reset output.

Applications

CD players, CD-ROM drives and other optical disc devices

Features

- 1) HSOP 28-pin package allows for miniaturization of applications.
- 2) Wide dynamic range.
- 3) Reset output pin.

- 4) Internal thermal shutdown circuit.
- 5) Gain is adjustable with an attached resistor.
- Internal 5V regulator. (attached PNP transistor required)
- 7) Internal standard operational amplifier.

●Absolute maximum ratings (Ta=25℃)

Parameter	Symbol	Limits	Unit
Power supply voltage	Vcc	18	V
Power dissipation	Pd	1700*1	mW
Operating temperature range	Topr	-30~85	°C
Storage temperature range	Tstg	-50~150	°C
Rated current	Юмвх.	1.4*2	Α

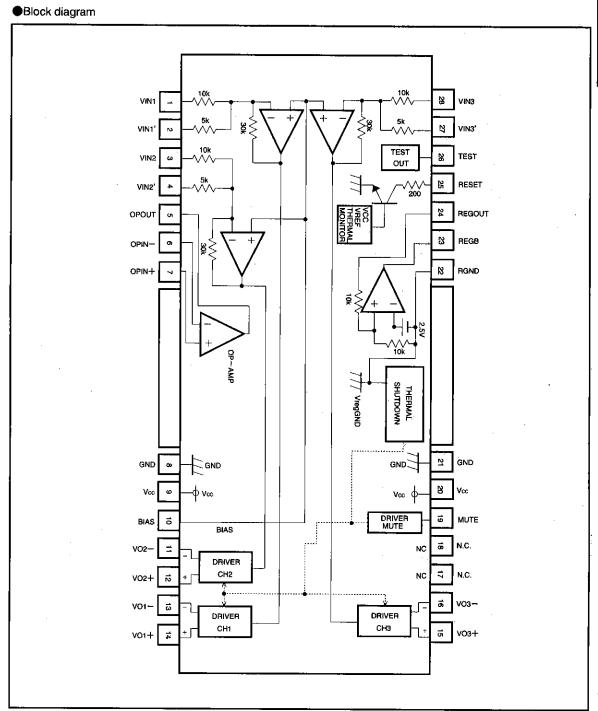
^{*1} When mounted to a 50 x 50 x 1.0 mm paper phendl board Reduced by 13.6 mW for each increase in Ta of 1°C over 25°C.

●Recommended operating conditions (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit
Power supply voltage	Voc	6	_	11	٧
Tower supply voltage	ver supply voltage Vcc		_	11	V*3

^{*3} Without regulator

^{*2} Within the range of power dissipation and safe operational area (ASO)



Pin descriptions

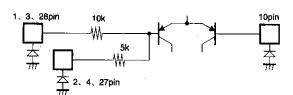
Pin No.	Pin name	Function
1	VIN1	Channel 1 input
2	VIN1'	Changing channel 1 gain
3	VIN2	Channel 2 input
4	VIN2'	Changing channel 2 gain
5	OPOUT	Operational amplifier output
6	OPIN-	Operational amplifier negative input
7	OPIN+	Operational amplifier positive input
8	GND	Substrate ground
9	Vcc	Vcc
10	BIAS	Bias input
11	VO2-	Channel 2 negative output
12	VO2+	Channel 2 positive output
13	VO1-	Channel 1 negative output
14	VO1+	Channel 1 positive output
15	VO3+	Channel 3 positive output
16	VO3-	Channel 3 negative output
17	N.C	
18	N.C	
19	MUTE	Mute control
20	Vcc	Vcc
21	GND	Substrate ground
22	RGND	Regulator ground
23	REGB	Connect to base of attached transistor
24	REGOUT	5 V output (Note 4)
25	RESET	Reset output
26	TEST	Test pin
27	VIN3'	Changing Channel 3 gain
28	VIN3	Channel 3 input

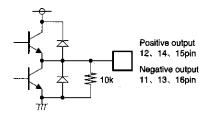
Notes: 1. "Driver positive output" and "driver negative output" indicate polarity relative to input.

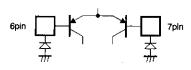
2. The radiating fin is internally shorted by pin 8 (GND).

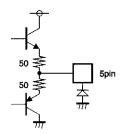
3. Pin 22 is the ground pin for the regular and internal voltage source and so must be connected to a ground even if the regulator is not used.

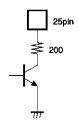
4. Attach a PNP transistor collector.

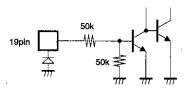


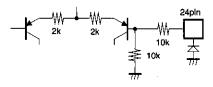


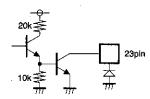












CD/CD-ROM Drivers (1 \sim 3 channels)

lacktriangle Electrical characteristics (unless otherwise noted, Ta=25°C, Vcc=8V, RL=8 Ω)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	Measurement Circuit
(Driver)							
Quiescent current	lo	1.5	5.0	7.5	mA	No load	Fig.1
Input voltage, offset	Voi	- 5	0	5	mV		Fig.1
Output voltage, offset	Voo	- 5	0	5	m∨		Fig.1
Dead zone	V _{DB}	10	20	30	mV	(Total for positive and negative)	Fig.1
Max. output amplitude	Vом	5.6	6.0	<u> </u>	V	Differential output	Fig.1
Voltage gain	Gvc	7.0	9.5	11.5	dB	Vin = 500 mV, differential output	Fig.1
Positive/negative output voltage gain differential	ΔGvc	-0.9	0	0.9	dΒ	as above	Fig.1
Ripple rejection	RR	_	80	_	dB	Vin=0.1Vrms、100Hz	Fig.1
Mute-off voltage	VMOFF	2.0		_	V		Fig.1
Mute-on voltage	VMON	_	_	0.5	٧		Fig.1
Reset-on threshold voltage	Vron	4.75	5.00	5.25	٧	Vcc reset-on voltage	Fig.1
Reset hysteresis voltage	ΔVRH	0.15	0.30	0.66	ν	Vcc reset hysteresis amplitude	Fig.1
Reset-off output voltage	VRESOFF	4.0	_	-	٧	30K Ω at 5V	Fig.1
Reset-on output voltage	VRESON	_	_	0.5	ν	as above	Fig.1
⟨5 V regulator⟩		<i>.</i>		*			
Output voltage	VREG	4.75	5.00	5.25	٧	IL=100mA	Fig.1
Output load differential	ΔVal	-50	0	10	m۷	I∟=0~200mA	Fig.1
Input variation	ΔVvcc	-10	0	40	mV	(Vcc=6~11V) l _L =100mA	Fig.1
Drop voltage	Voif	_	0.3	0.6	٧	Vcc=4.7V、lL=200mA *1	Fig.1
Vreg amplifier output current	IREG	8	20	_	mA	Vcc = 4.7V, 3 v impressed *2	Fig.1
(Operational amplifier)							
Offset voltage	Vofop	-5	0	5	mV		Fig.1
Input bias current	Івор	_	_	300	nΑ		Fig.1
Output voltage, H level	Vонор	6.5	7.2	_	V		Fig.1
Output voltage, L level	Volop			1.8	V		Fig.1
Output drive current (sink)	Isink	10	40	_	mA	50 Ω at Vcc	Fig.1
Output drive current (source)	Isource	10	40	_	mA	50 Ω at GND	Fig.1
Open loop voltage gain	Gvo		72	_	dB	Vin=-75dBV、1KHz	Fig.1
Slew rate	SR	_	1	_	V/μS	. 100 Hz square wave	Fig.1

O Not designed for radiation resistance

^{*1} When power transformer satisfies characteristic Vsat < 0.2 V at 200 mA (IC).

^{*2 24-}pin = open

Meassurement circuit

RL

REG2

CH3IN

MUTE ON 0.5V OFF 2.0V

2 + 1000 μF

2SB1132



Fig.1

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42

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#

-√ 1ΜΩ

B

10k 0 / 10k BHORT

CH2IN

	0	Measur	ement	circuit	switch	h tal	ole
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Commission				Switc	h					Ing	out	Note
Symbol	RL	CH1IN CH2IN CH3IN	RIPPLE	REG1	REG2	NF	OPIN	GVO	OPI	BIAS	MUTE	Note
(Driver)		,										are are a second and a second a
la	OFF	OFF	ON	ON	NORM	SHORT	OPEN	OFF	OPEN	2.5V	2V	
Voi	ON	1	1	1	1	↓	ţ	ţ	1	1	↓	
Voo	1	ON (2.5V)	‡	Ţ	1	1	ţ	ļ	ţ	1	Ţ	
VDB	1	ON (Approx. 2.5V)	Į.	Ţ	Ţ	Ţ	ţ	ţ	ļ	ļ	ļ	
Vом	1	ON (1V, 7V)	+	1	+	ţ	↓	. ↓	ļ	4V	1	
Gvc	1	ON (2V, 3V)	1	1	1	Ţ	ţ	ţ	1	2.5V	Ţ	
ΔGvc	1	ON (2V, 3V)	1	↓ .	1	1	ţ	ţ	ţ	↓	1	
RR	1	ON (2.5V)	OFF	1	1	ļ	1	ţ	ţ.	ţ	ļ.	SG1: 0.1Vrms、100Hz
VMOFF	1	ON (3V)	ON	ţ	1	ļ	ţ	ţ	ţ	1	1	
VMON	1	ON (3V)	1	1	Ţ	ţ	1	ţ	1	ţ	0.5V	
VRON	_	OFF	1	ţ	1	ţ	1	ţ	+	ţ	2V	
Δ Vян	_	ţ	ţ	ţ	1	ţ	1	ţ	ļ.	Ţ	1	
VRESON	-	1	1	1	+	ţ	↓	1	ţ	ļ	Ţ	
VRESOFF	-	Į.	ţ	ļ	+	ţ	1	+	1	ļ	Ţ	
VAESON	_	↓	1	<u> </u>	+	↓ .	1	1	Ţ	ļ	ţ	
(5 V reg	ulator					· · · · · · · · · · · · · · · · · · ·	-					
VREG	OFF	OFF	ON	ON	NORM	SHORT	OPEN	OFF	OPEN	2.5V	2V	IL=100mA
ΔVal	ţ	1	1	i	+	ţ	ţ	1	1	ļ	Ţ	L=0~200mA
ΔVvcc	1	1	ţ	ļ	ţ	ţ	ļ	Ţ	ţ	ţ	1	IL=100mA、 Vcc=6~11V
Voif	↓	1	1	<u> </u>	1	1	↓	1	1	i	1	Vcc=4.7A、lu=200mA
IREG	ţ	1	1	OFF	IREG	+	+	ţ	Į.	1	Ţ	Vcc=4.7A
(Operati	onal ar	mplifier)		'			ı			J		11.
Vorop	OFF	OFF	ON	ON	NORM	SHORT	OPEN	OFF	OPEN	2.5V	2V	
Івор	1	1	+	ţ	1	1M	1	Į.	ţ	1	ţ	"
Vонор	ţ	+	+	†	ļ	10k	GND	↓	Ţ	1	ļ	
VOLOP	ţ	+	+	Ţ	ţ	ţ	Vcc	1	ţ	1	1	
Isink .	ţ	↓	. ↓	1	ţ	SHORT	OPEN	Ţ	Vcc	+	+	
Isource	ļ	ļ	1	1	ţ	ţ	1	Ţ	GND	1	1	
Gvo	ţ	ţ	ţ	1	+	10k	Ţ	ON	Ţ	+	4	SG2: -75dBV、1kHz
SR	ţ	1	1	1	ļ	SHORT	↓	OFF	1	↓	ļ	SG3: 100 MHz, 3 Vp-p output

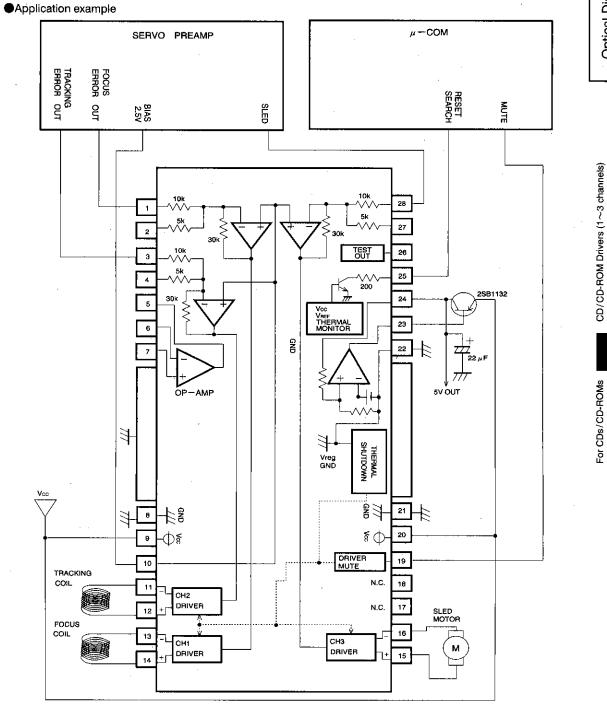


Fig.2

Operation notes

1. Relationship between reset output and muting

	Muting	Reset output
Supply voltage drop	OFF	'H' → 'L'
Bias drop	ON	'H' → 'L'
Thermal shutdow	ON	'H' → 'L'
Muting	ON	No change

Reset output changes to LOW when the supply voltage drops below 5.0V (typically) and changes to HIGH when the supply voltage rises above 5.3V (typically).

Bias drop

When the bias pin (pin 23) voltage drops below 1.4V, the circuit is muted and reset output changes to LOW.

Thermal shutdown

If the chip redues a temperature of 175°C (Typ.) or more, the circuit is muted and the reset output changes to LOW.

Muting

When the mute pin (pin 7) voltage is opened or lowered below 0.5V, the circuit is muted, but reset output does not change.

All three driver output channels are muted during thermal shutdown, muting and a drop in bias pin voltage. No other components are muted.

3. Dead zone

Dead zone width is determined as follows: Dead zone width=input resistance×1 μ A When using the internal resistor (10k Ω), dead zone width is 10mV (typically one side). Because the input resistance and 1 μ A temperature characteristics are canceled out, there is virtually no variation due to temperature as long as the internal input resistor is used. However, when connecting an attached resistor in series in order to change the gain, dead zone width varies according to temperature and is determined as follows:

Dead zone width= (internal input resistance+attached resistance) $\times 1 \mu A$

- 4. Be sure to connect the IC to a 0.1 μ F bypass capacitor to the power supply, at the base of the IC.
- The capacitor between regulator output (24 pin) and GND also serves to prevent oscillation of the IC, so select one with good temperature characteristics.
- 6. Pin 26 is the test pin and should be left open during normal operation.
- Pins 17 and 18 are NC pins and are not connected internally.

Electrical characteristic curves

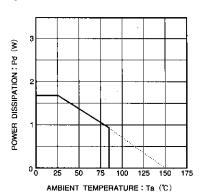


Fig. 3 Thermal derating curve

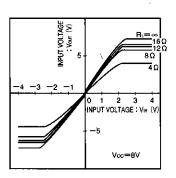


Fig. 4 Driver I/O characteristics (when load changes)

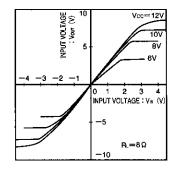


Fig. 5 Driver/O characteristics (when supply voltage changes)

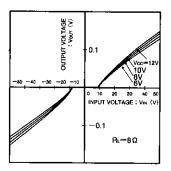


Fig. 6 Driver I/O characteristics when micro-input (when supply voltage changes)

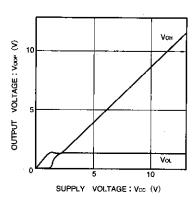


Fig. 7 Supply voltage vs. operational amplifier high level/low level voltage

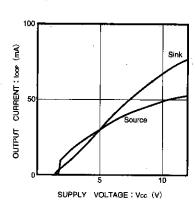


Fig. 8 Supply voltage vs. operational amplifier Output drive current

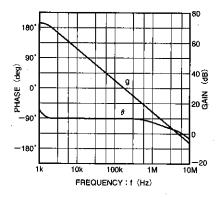


Fig. 9 Operational amplifier vs. open loop

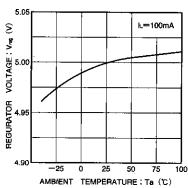


Fig. 10 Regulator voltage vs. temperature

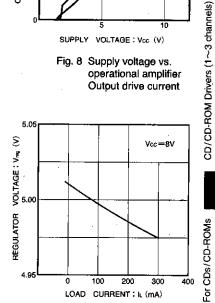
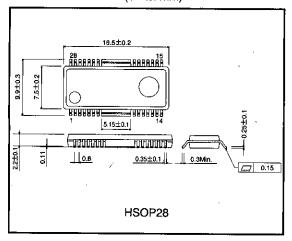


Fig. 11 Load current vs. regulator voltage

External dimensions (Units: mm)



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